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FSA3200 —Two-Port, High-Speed USB2.0 Switch with Mobile High-Definition Link (MHL™)

Features

- Low On Capacitance: 2.7 pF / 3.1 pF MHL / USB (Typical)
- Low Pow er Consumption: 30µA Maximum
- Supports MHL Rev. 2.0
- MHL Data Rate: 4.68 Gbps
- V_{BUS} Pow ers Device with No V_{CC}
- Packaged in 16-Lead UMLP (1.8 x 2.6 mm)
- Over-Voltage Tolerance (OVT) on all USB Ports
 Up to 5.25 V without External Components

Applications

Cell Phones and Digital Cameras

Description

The FSA3200 is a bi-directional, low-power, two-port, high-speed, USB2.0 and video data switch. Configured as a double-pole, double-throw (DPDT) switch for data and a single-pole, double-throw (SPDT) switch for ID; it is optimized for switching between high- or full-speed USB and Mobile Digital Video sources (MDV), including supporting the MHLTM Rev. 2.0 specification.

The FSA3200 contains special circuitry on the switch VO pins, for applications where the V_{CC} supply is powered off (V_{CC} =0), that allows the device to withstand an over-voltage condition. This switch is designed to minimize current consumption even when the control voltage applied to the control pins is lower than the supply voltage (V_{CC}). This feature is especially valuable to mobile applications, such as cell phones, allowing direct interface with the general-purpose VOs of the baseband processor. Other applications include switching and connector sharing in portable cell phones, digital cameras, and notebook computers.

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSA3200UMX	GB	-40 to +85°C	16-Lead, Ultrathin Molded Leadless Package (UMLP), 1.8 x 2.6 mm

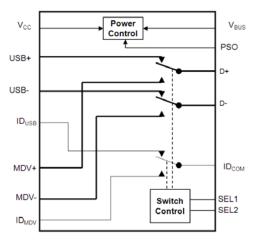


Figure 1. Analog Symbol

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Switch Power Operation

In normal operation, the FSA3200 is powered from the V_{CC} pin, which typically is derived from a regulated power management device. In special circumstances, such as production test or system firmware upgrade, the device can be powered from the V_{BUS} pin. In this mode of operation, a valid V_{BUS} voltage is present (per USB2.0 specification) and $V_{CC}=0$ V, typically due to a no-battery condition. With the SELn pins strapped LOW (via external resistor), the FSA3200 closes the USB path, enabling the initial programming of the system directly from the USB connector. Once the system has normal

operating supply power with V_{CC} present, the V_{BUS} supply is not utilized and normal switch operation commences. Optionally, the Power Select Override (PSO) pin can be set HIGH to force the device to be powered from V_{BUS} .

The V_{BUS} / V_{CC} detection capability is not intended to be an accurate determination of the voltages present, rather a state condition detection to determine which supply should be used. These state determinations rely on the voltage conditions as described in the Electrical Characterization tables below .

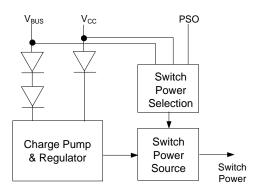


Figure 2. Simplified Logic of Switch Power Selection Circuit

Table 1. Switch Power Selection Truth Table

V _{cc}	V _{BUS}	PSO ⁽¹⁾	Switch Power Source
0	0	0	No switch power, switch paths high-Z
0	1	0	V _{BUS}
1	0	0	Vcc
1	1	0	Vcc
0	0	1	No sw itch pow er, sw itch paths high-Z
0	1	1	V _{BUS}
1	0	1	Vcc ⁽²⁾
1	1	1	V _{BUS}

Notes:

- 1. Control inputs should never be left floating or unconnected. If the PSO function is used, a weak pull-up resistor $(3 \text{ M}\Omega)$ should be used to minimize static current draw. If the PSO function is not used, tie directly to GND.
- PSO control is overridden with no V_{BUS} and the power selection is switched to V_{CC}.

Table 2. Data Switch Select Truth Table

SEL1 ⁽³⁾	SEL2 ⁽³⁾	Function
0	0	D+/D- connected to USB+/USB-, IDco connected to IDusB
0	1	D+/D- connected to USB+/USB-, IDcom connected to ID _{MDV}
1	0	D+/D- connected to MDV+/MDV-, ID _{COM} connected to ID _{USB}
1	1	D+/D- connected to MDV+/MDV-, IDcom connected to ID _{MDV}

Note:

3. Control inputs should never be left floating or unconnected. To guarantee default sw itch closure to the USB position, the SEL pins should be tied to GND with a weak pull-down resistor ($3\,\mathrm{M}\Omega$) to minimize static current draw.

Pin Configuration

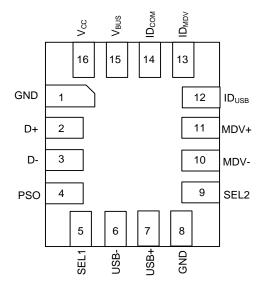


Figure 3. Pin Assignments (Top-Through View)

Pin Definitions

Pin#	Name	Description
1	GND	Ground
2	D+	Data Switch Output (Positive)
3	D-	Data Switch Output (Negative)
4	PSO	Pow er Select Override
5	SEL1	Data Switch Select
6	USB-	USB Differential Data (Negative)
7	USB+	USB Differential Data (Positive)
8	GND	Ground
9	SEL2	ID Switch Select
10	MDV-	MDV Differential Data (Negative)
11	MDV+	MDV Differential Data (Positive)
12	IDusa	ID Switch MUX Output for USB
13	ID _{MDV}	ID Switch MUX Output for MDV
14	ID _{COM}	ID Switch Common
15	V _{BUS}	Device Power when Vcc Not Available
16	V _{CC}	Device Pow er from System ⁽⁴⁾

Note:

4. Device automatically switches from V_{BUS} when valid V_{CC} minimum voltage is present.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit
Vcc, V _{BUS}	Supply Voltage		-0.5	5.5	V
VCNTRL	DC Input Voltage (SELn, PSO) ⁽⁵⁾		-0.5	Vcc	V
V _{SW} ⁽⁶⁾	DC Switch I/O Voltage ⁽⁵⁾		-0.50	5.25	V
I _{IK}	DC Input Diode Current		-50		mA
ЮПТ	DC Output Current			100	mA
T _{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	
	Human Body Model, JEDEC: JESD22-A114	All Pins		3.5	
ESD	IEC 61000-4-2, Level 4, for D+/D- and V _{CC} Pins ⁽⁷⁾	Contact		8.0	kV
ESD	IEC 61000-4-2, Level 4, for D+/D- and V _{CC} Pins ⁽⁷⁾	Air		15.0	KV.
	Charged Device Model, JESD22-C101			2.0	

Notes:

- 5. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.
- 6. V_{SW} refers to analog data sw itch paths (USB, MDV, and ID).
- 7. Testing performed in a system environment using TVS diodes.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{BUS}	Supply Voltage Running from V _{BUS} Voltage	4.20	5.25	V
Vcc	Supply Voltage Running from V _{CC}	2.7	4.5	V
t _{RAMP} (VBUS)	Pow er Supply Slew Rate from V _{BUS}	100	1000	μs/V
t _{RAMP(VCC)}	Pow er Supply Slew Rate from V _{CC}	100	1000	μs/V
Θ_{JA}	Thermal Resistance		336	C°/W
V _{CNTRL}	Control Input Voltage (SELn, PSO) ⁽⁸⁾	0	4.5	V
V _{SW(USB)}	Switch I/O Voltage (USB and ID Switch Paths)	-0.5	3.6	V
V _{SW(MDV)}	Sw itch I/O Voltage (MDV Sw itch Path)	1.65	3.45	V
T _A	Operating Temperature	-40	+85	°C

Note:

8. The control inputs must be held HIGH or LOW; they must not float.

DC Electrical Characteristics

All typical value are at $T_A=25^{\circ}C$ unless otherwise specified.

Cumbal	Doromotor	Candition	V 00	T _A =- 4	10°C to	+85°C	l lm:4
Symbol	Parameter	Condition	V _{cc} (V)	Min.	Тур.	Max.	Unit
Vıĸ	Clamp Diode Voltage	I _{IN} =-18 mA	2.7			-1.2	V
V _{IH}	Control Input Voltage High	SELn, PSO	2.7 to 4.3	1.25			V
VIL	Control Input Voltage Low	SELn, PSO	2.7 to 4.3			0.6	V
lιΝ	Control Input Leakage	V _{SW} =0 V to 3.6 V, V _{CNTRL} =0 V to 1.98 V	4.3	-1		1	μA
loz(MDV)	Off-State Leakage for Open MDV Data Paths	V_{SW} =1.65 $V \le MDV$ $\le 3.45 V$	4.3	-1		1	μA
loz(USB)	Off-State Leakage for Open USB Data Paths	V _{SW} =0 V ≤ USB ≤ 3.6 V	4.3	-1		1	μA
loz(ID)	Off-State Leakage for Open ID Data Path	$V_{SW}=0 \ V \le \ ID \le 3.6 \ V$	4.3	-0.5		0.5	μA
ICL(MDV)	On-State Leakage for Closed MDV Data Paths ⁽⁹⁾	V_{SW} =1.65 $V \le MDV$ $\le 3.45 V$	4.3	-1		1	μA
I _{CL(USB)}	On-State Leakage for Closed USB Data Paths ⁽⁹⁾	V _{SW} =0 V ≤ USB ≤ 3.6 V	4.3	-1		1	μA
I _{CL(ID)}	On-State Leakage for Closed ⁽⁹⁾ ID Data Path	$V_{SW}=0 \ V \le \ ID \le 3.6 \ V$	4.3	-0.5		0.5	μA
loff	Pow er-Off Leakage Current (All I/O Ports)	V _{SW} =0 V or 3.6 V, Figure 5	0	-1		1	μA
R _{ON(USB)}	HS Switch On Resistance (USB to D Path)	V _{SW} =0.4 V, l _{ON} =-8 mA Figure 4	2.7		3.9	6.5	Ω
Ron(MDV)	HS Switch On Resistance (MDV to D Path)	V _{SW} =V _{CC} -1050mV, l _{ON} =-8mA, Figure 4	2.7		5		Ω
R _{ON(ID)}	LS Switch On Resistance (ID Path)	V _{SW} =3V, I _{ON} =-8mA Figure 4	2.7		12		Ω
$\Delta R_{ON(MDV)}$	Difference in R _{ON} Between MDV Positive-Negative	V _{SW} =V _{CC} -1050 mV, l _{ON} =-8 mA, Figure 4,	2.7		0.03		Ω
$\Delta R_{ON(USB)}$	Difference in R _{ON} Between USB Positive-Negative	V _{SW} =0.4 V, l _{ON} =-8 mA Figure 4	2.7		0.18		Ω
$\Delta R_{ON(ID)}$	Difference in R _{ON} Between ID Switch Paths	V _{SW} =3 V, I _{ON} =-8 mA Figure 4	2.7		0.4		Ω
Ronf(MDV)	Flatness for R _{ON} MDV Path	V _{SW} =1.65 V to 3.45 V, I _{ON} =-8 mA, Figure 4	2.7		1		Ω
lvaus	V _{BUS} Quiescent Current	V _{BUS} =5.25 V, V _{CNTRL} =0 V or 1.98 V, l _{OUT} =0	4.3			100	μΑ
lcc	V _{CC} Quiescent Current	V _{BUS} =0 V, V _{CNTRL} =0 V or 1.98 V, l _{OUT} =0	4.3			30	μA

Note:

9. For this test, the data switch is closed with the respective switch pin floating.

AC Electrical Characteristics

All typical value are for V_{CC} =3.3 V and T_A =25°C unless otherwise specified.

Cumbal	Davamatav	Candition	v (\(\(\) \)	T _A =- 4	0°C to	+85°C	Unit
Symbol	Parameter	Condition	V _{CC} (V)	Min.	Тур.	Max.	Unit
t _{ON}	Turn-On Time, SELn to Output	R _L =50 Ω, C _L =5 pF, V _{SW(USB)} =0.8 V, V _{SW(MDV)} =3.3 V, Figure 6, Figure 7	2.7 to 3.6		445	600	ns
t _{OFF}	Turn-Off Time, SELn to Output	$ \begin{array}{l} R_L \!\!=\!\! 50~\Omega,~C_L \!\!=\!\! 5~pF, \\ V_{SW(USB)} \!\!=\!\! 0.8~V,~V_{SW(MDV)} \!\!=\!\! 3.3V, \\ Figure~6,~Figure~7 \end{array} $	2.7 to 3.6		125	300	ns
t _{PD}	Propagation Delay ⁽¹⁰⁾	C_L =5 pF, R_L =50 Ω , Figure 6, Figure 8	2.7 to 3.6		0.25		ns
t _{BBM}	Break-Before-Make ⁽¹⁰⁾	$$\rm R_{L}$=50~\Omega,~C_{L}$=5~pF,$$\rm V_{ID}$=V_{MDV}$=3.3~V,~V_{USB}$=0.8~V,$\rm Figure~10$	2.7 to 3.6	2.0		13	ns
O _{IRR(MDV)}	Off Isolation ⁽¹⁰⁾	V_S =1 V_{pk-pk} , R_L =50 Ω , f=240 MHz, Figure 12	2.7 to 3.6		-45		dB
O _{IRR(USB)}	On Solation	V_S =400m $V_{pk\cdot pk}$, R_L =50 Ω , f=240MHz, Figure 12	2.7 to 3.6		-38		dB
Xtalk _{MDV}	Non-Adjacent Channel ⁽¹⁰⁾	V_S =1 V_{pk-pk} , R_L =50 Ω , f=240 MHz, Figure 13	2.7 to 3.6		-44		dB
Xtalk _{USB}	Crosstalk	V_S =400 mV $_{pk\cdot pk}$, RL=50 Ω , f=240 MHz, Figure 13	2.7 to 3.6		-39		dB
		V _{IN} =1 V _{pk-pk} , MDV Path, R _L =50 Ω, C _L =0 pF, Figure 11, Figure 16			2.34		GHz
BW	Differential -3 db Bandw idth ⁽¹⁰⁾	V_{IN} =400 m $V_{\text{pk-pk}}$, USB Path, R _L =50 Ω , C _L =0 pF, Figure 11, Figure 17	2.7 to 3.6		1.59) ! !
		ID Path, R _L =50 Ω , C _L =0 pF, Figure 11			100		MHz

Note:

10. Guaranteed by characterization.

USB High-Speed AC Electrical Characteristics

Typical values are at T_A = -40°C to +85°C.

Symbol	Parameter	Condition	V _{cc} (V)	Тур.	Unit
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽¹¹⁾	$C_L=5$ pF, $R_L=50$ Ω , Figure 9	3.0 to 3.6	3	ps
tJ	Total Jitter ⁽¹¹⁾	R _L =50 Ω , C _L =5 pf, t _R =t _F =500 ps (10-90%) at 480 Mbps, PN7	3.0 to 3.6	15	ps

Note:

11. Guaranteed by characterization.

MDV AC Electrical Characteristics

Typical values are at T_A = -40°C to +85°C.

Symbol	Parameter	Condition	V _{cc} (V)	Тур.	Unit
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽¹²⁾	R _{PU} =50 Ω to V _{CC} , C _L =0 pF	3.0 to 3.6	3	ps
tJ	Total Jitter ⁽¹²⁾	f=2.25 Gbps, PN7, R _{PU} =50 Ω to V _{CC} , C _L =0 pF	3.0 to 3.6	15	ps

Note:

12. Guaranteed by characterization.

Capacitance

Typical values are at T_A = -40°C to +85°C.

Symbol	Parameter	Condition	Тур.	Unit
C _{IN}	Control Pin Input Capacitance (13)	V _{CC} =0 V, f= 1 MHz	1.5	
C _{ON(USB)}	USB Path On Capacitance (13)	V _{CC} =3.3 V, f=240 MHz, Figure 15	3.1	
Coff(USB)	USB Path Off Capacitance (13)	V _{CC} =3.3 V, f=240 MHz, Figure 14	1.6	pF
C _{ON(MDV)}	MDV Path On Capacitance ⁽¹³⁾	V _{CC} =3.3 V, f=240 MHz, Figure 15	2.7	
C _{OFF(MDV)}	MDV Path Off Capacitance (13)	V _{CC} =3.3 V, f=240 MHz, Figure 14	1.1	

Note:

13. Guaranteed by characterization.

Test Diagrams

Note:

14. HSD refers to the high-speed data USB or MDV paths.

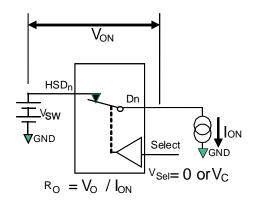
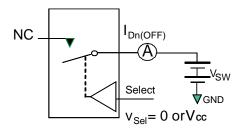
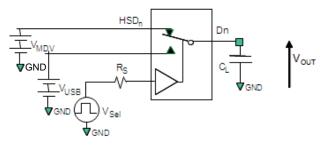


Figure 4. On Resistance



**Each switch port is tested separately

Figure 5. Off Leakage



 $R_{S}, \mbox{ and } C_{L} \mbox{ are functions of the application}$ environment (see AC Tables for specific values) $C_{L} \mbox{ includes test fixture and stray capacitance}.$

Figure 6. AC Test Circuit Load

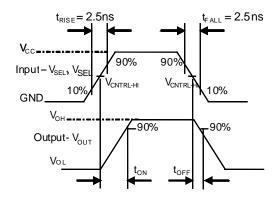


Figure 7. Turn-On / Turn-Off Waveforms

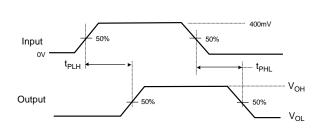


Figure 8. Propagation Delay (t_Rt_F - 500 ps)

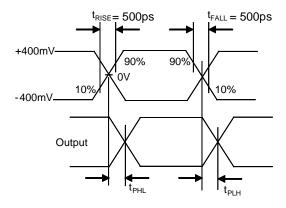


Figure 9. Intra-Pair Skew Test t_{SK(P)}

Test Diagrams (Continued)

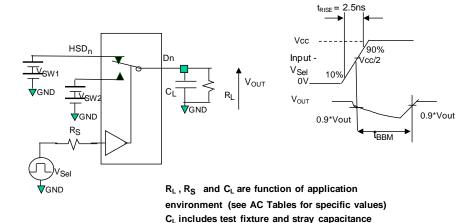


Figure 10. Break-Before-Make Interval Timing

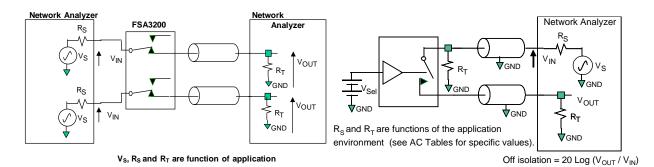


Figure 11. Insertion Loss

environment (see AC/DC Tables for values)

Figure 12. Channel Off Isolation

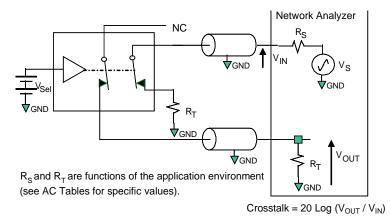


Figure 13. Non-Adjacent Channel-to-Channel Crosstalk

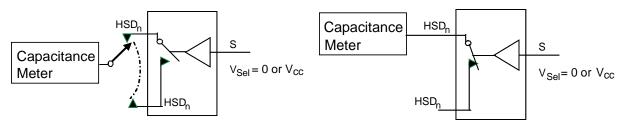


Figure 14. Channel Off Capacitance

Figure 15. Channel On Capacitance

Insertion Loss

One of the key factors for using the FSA3200 in mobile digital video applications is the small amount of insertion loss experienced by the received signal as it passes through the switch. This results in minimal degradation of the received eye. One of the ways to measure the quality of the high data rate channels is using balanced

ports and 4-port differential S-parameter analysis, particularly SDD21.

Bandwidth is measured using the S-parameter SDD21 methodology. Figure 16 shows the bandwidth (GHz) for the MDV path and Figure 17 the bandwidth curve for the USB path.

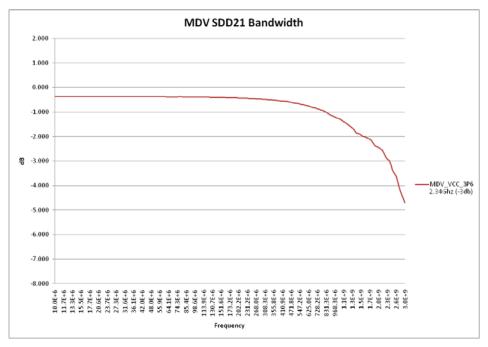


Figure 16. MDV Path SDD21 Insertion Loss Curve

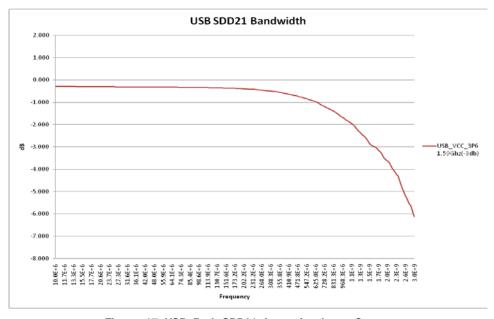


Figure 17. USB Path SDD21 Insertion Loss Curve

Typical Applications

Figure 18 shows the FSA3200 utilizing the $V_{\hbox{\scriptsize BUS}}$ connection from the micro-USB connector. The 3M resistor is used to ensure, for manufacturing test via the micro-USB connector, that the FSA3200 configures for

connectivity through the FSA9280A accessory switch. Figure 19 shows the configuration for the FSA3200 "self pow ered" by the battery only.

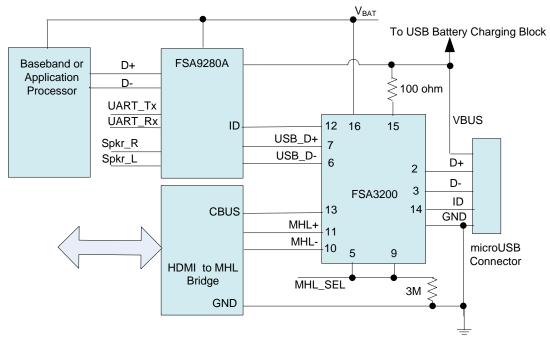


Figure 18. Typical FSA3200 Application Using V_{BUS}

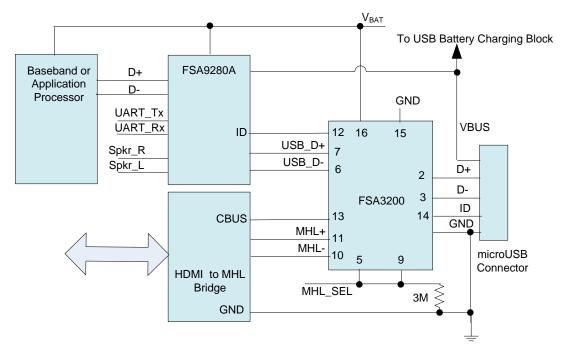
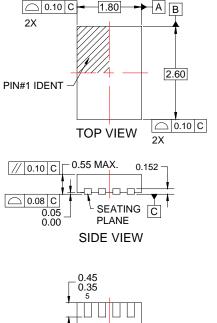
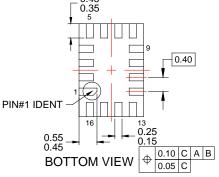


Figure 19. Typical FSA3200 "Self-Powered" Application Using VBAT

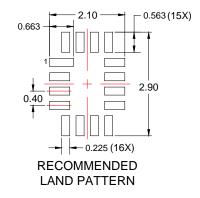
Physical Dimensions



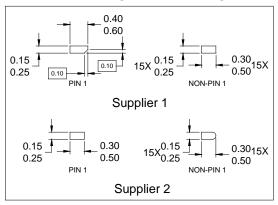


NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC STANDARD.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY.
- E. DRAWING FILENAME: MKT-UMLP16Arev4.
- F. TERMINAL SHAPE MAY VARY ACCORDING TO PACKAGE SUPPLIER, SEE TERMINAL SHAPE VARIANTS.



TERMINAL SHAPE VARIANTS



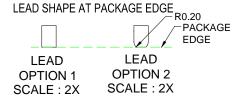


Figure 20. 16-Lead, Ultrathin Molded Leadless Package (UMLP)

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